

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



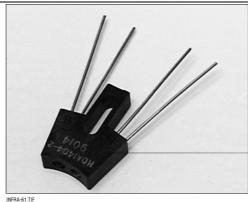




### **Reflective Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (- 55°C to +100°C)



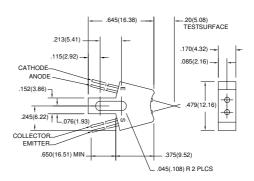
#### DESCRIPTION

The HOA1404 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1404-001,-002) or photodarlington (HOA1404-003), encased side-by-side on converging optical axes, in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1404 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is acetal copolymer. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_037.ds4



### **Reflective Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	l₅=20 mA
Reverse Leakage Current	I <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1404-001, -002 HOA1404-003	V <sub>(BR)</sub> CEO	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current HOA1404-001, -002 HOA1404-003	ICEO			100 250	nA	V <sub>CE</sub> =10 V I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1404-001 HOA1404-002 HOA1404-003	Ic(on)	0.2 0.8 2.0			mA	V <sub>CE</sub> =5 V I <sub>F</sub> =30 mA
Collector-Emitter Saturation Voltage HOA1404-001 HOA1404-002 HOA1404-003	VCE(SAT)			0.4 0.4 1.1	V	I <sub>F</sub> =30 mA <sup>(1)</sup> I <sub>C</sub> =30 μA I <sub>C</sub> =100 μA I <sub>C</sub> =250 μA
Rise And Fall Time HOA1404-001, -002 HOA1404-003	t <sub>r</sub> , t <sub>f</sub>		15 75		μs	$V_{CC}$ =5 V, I <sub>C</sub> =1 mA $R_L$ =1000 $\Omega$ $R_L$ =100 $\Omega$

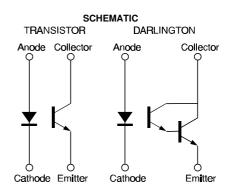
#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -55°C to 100°C Storage Temperature Range -55°C to 125°C Soldering Temperature (10 sec) 260°C

IR EMITTER

Power Dissipation 75 mW (1) Reverse Voltage 3 V 50 mA Continuous Forward Current **DETECTOR** TRANS.

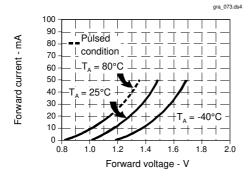
**DARLINGTON** 30 V 15 V Collector-Emitter Voltage **Emitter-Collector Voltage** 5 V 5 V 75 mW (1) 75 mW <sup>(1)</sup> Power Dissipation Collector DC Current 30 mA 30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible. Honeywell

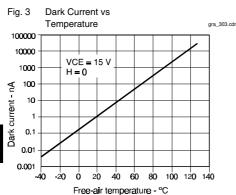
Notes
1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.20 in.(5.0 mm) from the front surface of the

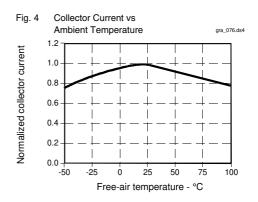
### **Reflective Sensor**

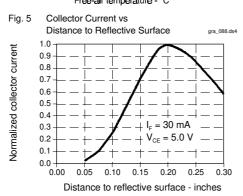


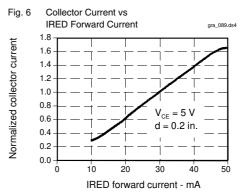
IRED Forward Bias Characteristics

Non-Saturated Switching Time vs Load Resistance gra\_079.ds4 1000 ≡ı≡⊞ Response time - µs 100 Photodarlington = | | Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms









All Performance Curves Show Typical Values

Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Reflective Sensor